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N-Channel SuperFET[®] MOSFET

600 V, 3.9 A, 1.2 Ω

Features

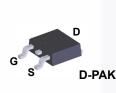
- 650 V @T_J = 150 °C
- Typ. R_{DS(on)} = 1.0 Ω
- Ultra Low Gate Charge (Typ. Q_g = 12.8 nC)
- Low Effective Output Capacitance (Typ. C_{oss}.eff = 32 pF)
- 100% Avalanche Tested
- RoHS Compliant

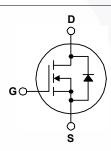
Applications

Lighting

· Solar Inverter

AC-DC Power Supply





MOSFET Maximum Ratings T_C = 25°C unless otherwise noted

Symbol		Parameter	FCD4N60TM	Unit	
V _{DSS}	Drain to Source Voltage		600	V	
I _D	Drain Current	- Continuous (T _C = 25 ^o C)		3.9	Α
	Drain Current	- Continuous (T _C = 100 ^o C)		2.5	A
I _{DM}	Drain Current	- Pulsed	- Pulsed (Note 1)		Α
V _{GSS}	Gate to Source Voltage			±30	V
E _{AS}	Single Pulsed Avalanche Energy		(Note 2)	128	mJ
I _{AR}	Avalanche Current		(Note 1)	3.9	Α
E _{AR}	Repetitive Avalanche Energy		(Note 1)	5.0	mJ
dv/dt	Peak Diode Recovery dv/dt		(Note 3)	4.5	V/ns
P _D	Dower Dissinction	(T _C = 25 ^o C)		50	W
	Power Dissipation	- Derate above 25°C		0.4	W/ºC
T _J , T _{STG}	Operating and Storage Temperature Range			-55 to +150	°C
TL	Maximum Lead Temperature for Soldering Purpose, 1/8" from Case for 5 Seconds			300	°C

Thermal Characteristics

Symbol	Parameter	FCD4N60TM	Unit
$R_{ ext{ heta}JC}$	Thermal Resistance, Junction to Case, Max.	2.5	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient, Max.	83	°C/W



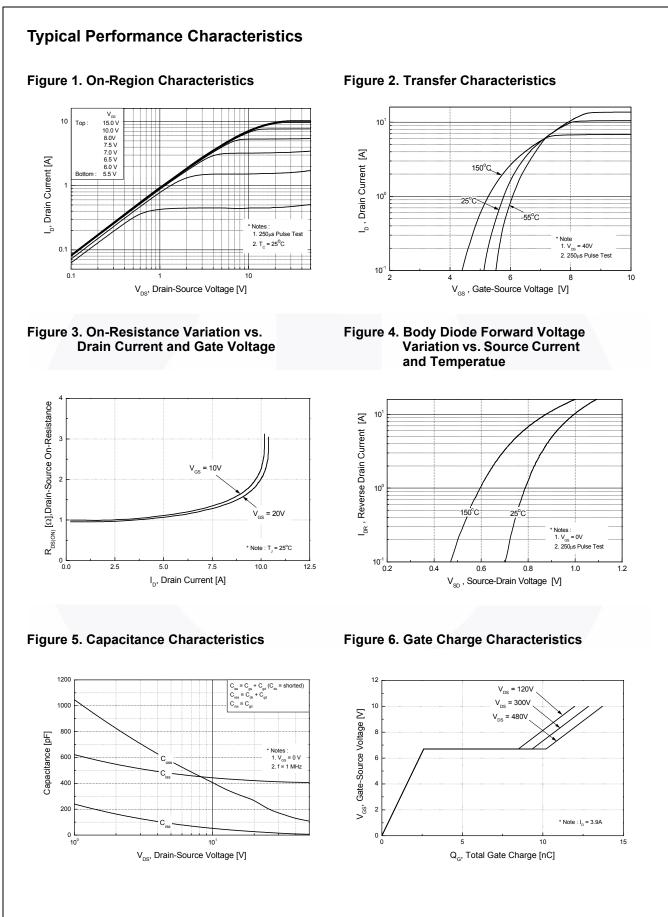
October 2013

FCD4N60 — N-Channel SuperFET[®] MOSFET

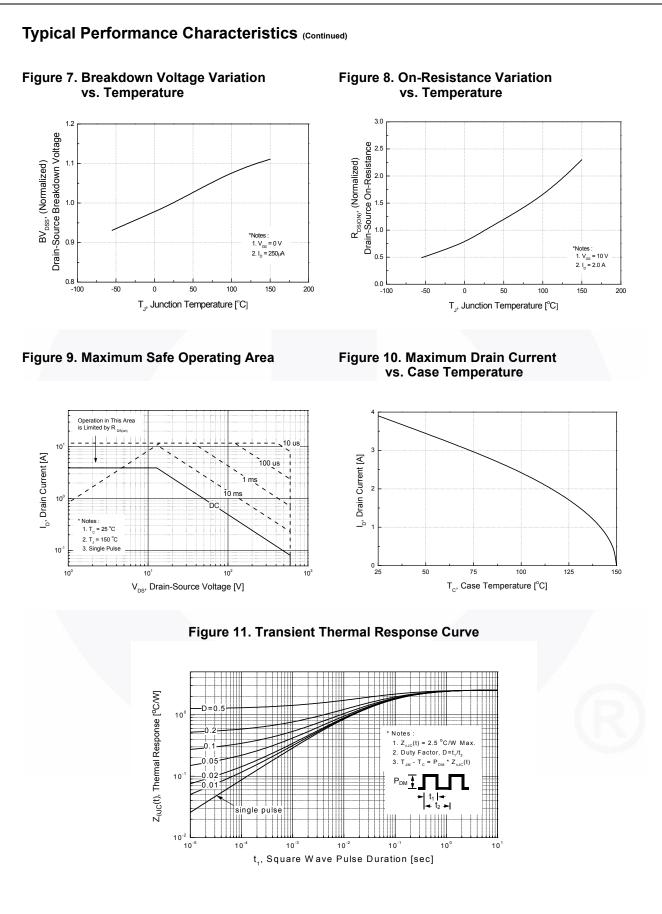
Description SuperFET[®] MOSFET is Fairchild Semiconductor's first generation of high voltage super-junction (SJ) MOSFET family that is utilizing charge balance technology for outstanding low onresistance and lower gate charge performance. This technology is tailored to minimize conduction loss, provide superior switching performance, dv/dt rate and higher avalanche energy. Consequently, SuperFET MOSFET is very suitable for the switching power applications such as PFC, server/telecom power, FPD TV power, ATX power and industrial power applications.

Device MarkingDevicePackFCD4N60FCD4N60TMD-P/		Device	Packa	nge	Reel Size	Таре	e Width		Quantit	y
				16m		2500				
			25°C unles	s otherwi						
Symbol		Parameter			Test Conditions		Min.	Тур.	Max.	Unit
Off Charac	teristic	S							1	-
BV _{DSS}	Drain to	Source Breakdown Vo	ltage	V_{GS} = 0 V, I_{D} = 250 µA, T_{C} = 25°C		600	-	-	V	
				$V_{GS} = 0 V, I_D = 250 \mu A, T_C = 150^{\circ}C$ $I_D = 1 mA, Referenced to 25^{\circ}C$		-	650	-	V	
ABV _{DSS}		own Voltage Temperatu	ire			-	0.6	-	V/ºC	
$/ \Delta T_J$ Coefficient BV _{DS} Drain-Source Avalanch		ource Avalanche Break	Breakdown							
0,02	Voltage			$V_{GS} = 0 V, I_D = 3.9 A$		-	700	-	V	
1	Zoro Co	ta Valtaga Drain Curra	nt	V _{DS} =	600 V, V _{GS} = 0 V		-	-	1	^
DSS	Zelo Ga	ite Voltage Drain Curre	111		480 V, T _C = 125 ^o C		-	-	10	μA
I _{GSS}	Gate to	Body Leakage Current		V _{GS} =	±30 V, V _{DS} = 0 V		-	-	±100	nA
On Charac	teristic									
V _{GS(th)}	-	reshold Voltage		Voo =	V _{DS} , I _D = 250 μA		3.0	-	5.0	V
R _{DS(on)}		rain to Source On Resi	stance		10 V, I _D = 2.0 A		-	1.0	1.2	Ω
9FS		Transconductance	otarioc		$40 \text{ V}, \text{ I}_{\text{D}} = 2.0 \text{ A}$		-	3.2	-	S
				.03				0.2		0
Dynamic C	haracte	eristics								-
C _{iss}	Input Ca	apacitance		V _{DS} = 25 V, V _{GS} = 0 V f = 1.0 MHz		-	415	540	pF	
C _{oss}	Output (Capacitance				-	210	275	pF	
C _{rss}		Transfer Capacitance				-	19.5	-	pF	
C _{oss}		Capacitance			480 V, V _{GS} = 0 V, f = 7		-	12	16	pF
C _{oss} eff.	Effective Output Capacitance			V_{DS} = 0 V to 400 V, V_{GS} = 0 V		-	32	-	pF	
Switching	Charact	teristics								
t _{d(on)}	Turn-On Delay Time Turn-On Rise Time		V _{DD} = 300 V, I _D = 3.9 A		-	16	45	ns		
t _r					-	45	100	ns		
t _{d(off)}	Turn-Off	Delay Time		$R_{G} = 25 \Omega$ (Note 4)		-	36	85	ns	
t _f		Fall Time				-	30	70	ns	
Q _{g(tot)}	Total Ga	te Charge at 10V		Vpc =	480 V, I _D = 3.9 A,			12.8	16.6	nC
Q _{gs}	Gate to	Source Gate Charge		$V_{GS} = 10 V$		-	2.4	-	nC	
Q _{gd}	Gate to	Gate to Drain "Miller" Charge		(Note 4)			-	7.1	-	nC
		le Characteristics	•							
_	1			do Convo	rd Current				20	•
l _S	Maximum Continuous Drain to Source Did					-	-	3.9 11.7	A	
I _{SM}		Maximum Pulsed Drain to Source Diode F Drain to Source Diode Forward Voltage				-		1.4	A	
V _{SD}		Recovery Time	vollage	$V_{GS} = 0 V, I_{SD} = 11 A$ $V_{GS} = 0 V, I_{SD} = 11 A$ $dI_{F}/dt = 100 A/\mu s$		-	277	-	ns	
t _{rr}		-						_		
Q _{rr}	Reverse	Recovery Charge					-	2.07		μC

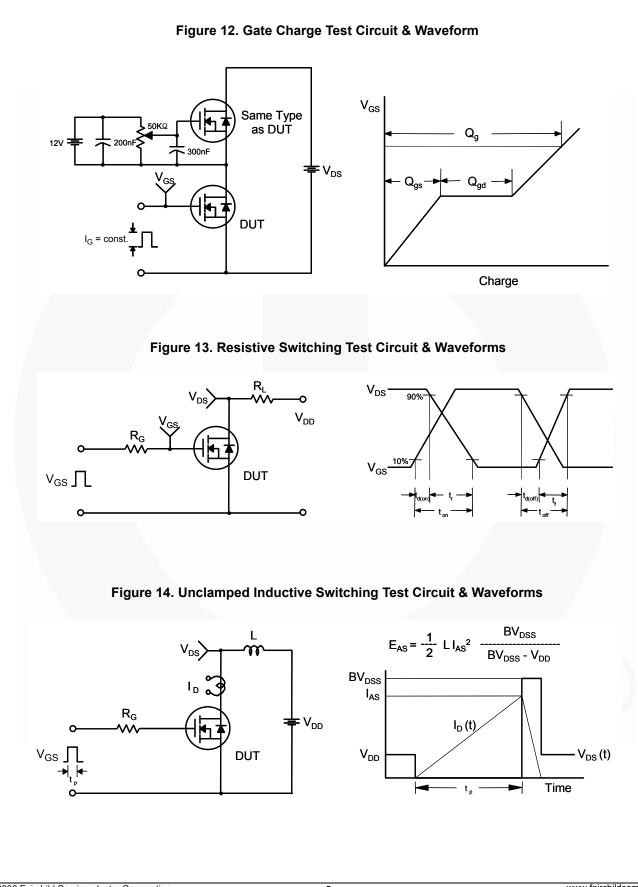




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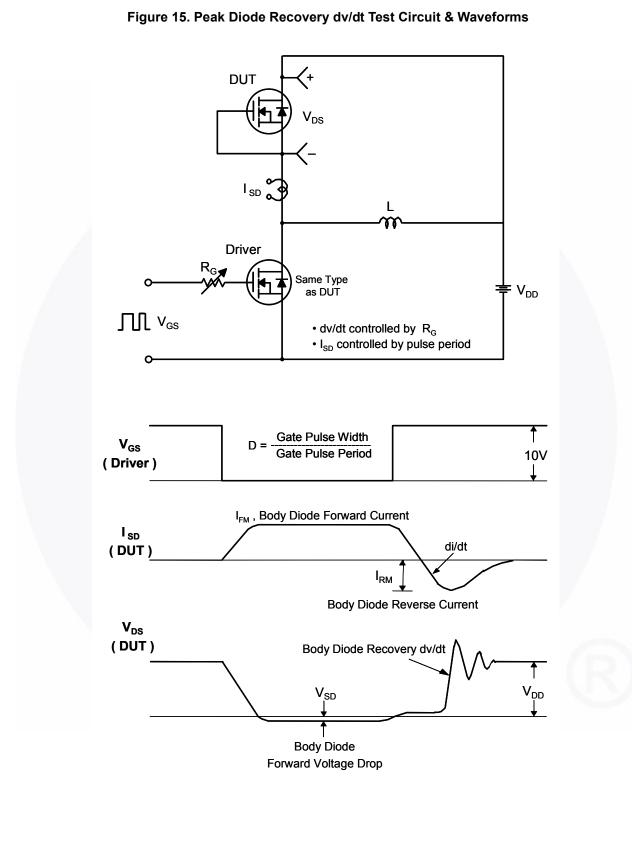


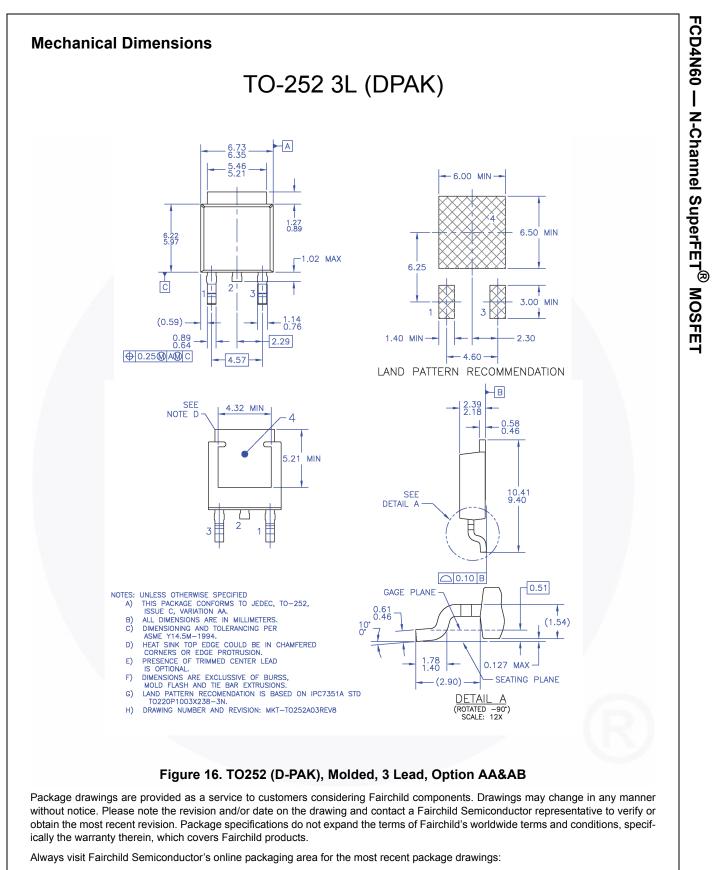
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Dimension in Millimeters



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